Low-voltage digital IF receiver SA637

DESCRIPTION

The SA637 is a low-voltage high performance monolithic digital system with high-speed RSSI incorporating a mixer, oscillator with buffered output, two limiting intermediate frequency amplifiers, fast logarithmic received signal strength indicator (RSSI), voltage regulator, RSSI op amp and power down pin. The SA637 is available in SSOP (shrink small outline package).

The SA637 was designed for portable digital communication applications and will function down to 2.7V. The limiter amplifier has differential outputs with 2MHz small signal bandwidth. The RSSI output has access to the feedback pin. This enables the designer to level adjust the outputs or add filtering.

FEATURES

- V_{CC} = 2.7 to 5.5V
- Low power receiver (3.8mA @ 3V)
- Power down mode (I_{CC} = 110µA)
- Fast RSSI rise and fall times
- Extended RSSI range with temperature compensation
- RSSI op amp
- 2MHz limiter small signal bandwidth
- 455kHz filter matching (1.5kΩ)
- Differential limiter output

PIN CONFIGURATION

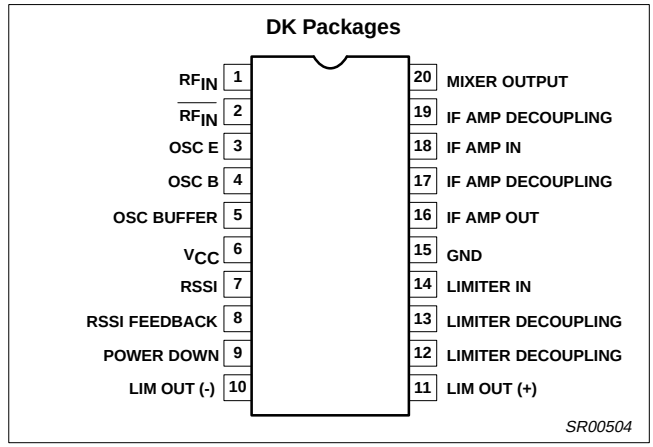


Figure 1. Pin Configuration

- Oscillator buffer
- SSOP-20 package

APPLICATIONS

- ADC (American Digital Cellular)
- Digital receiver systems
- Cellular radio

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
20-Pin Plastic Shrink Small Outline Package (Surface-mount)	-40 to +85°C	SA637DK	SOT266-1

BLOCK DIAGRAM

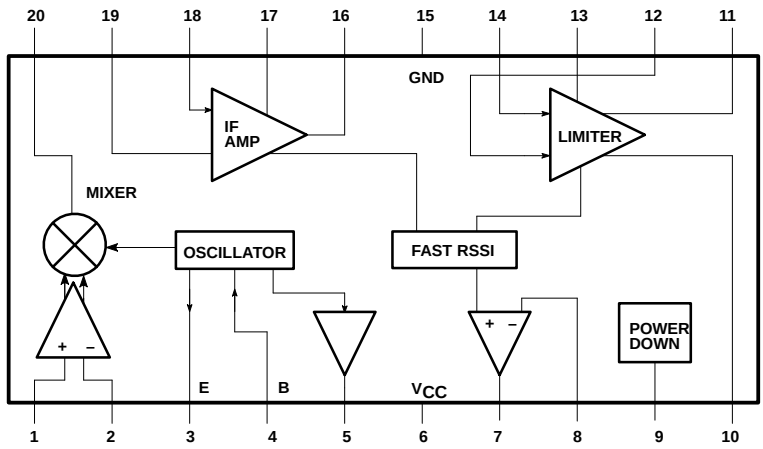


Figure 2. Block Diagram

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V_{CC}	Supply voltage	-0.3 to +6.0	V
V_{IN}	Voltage applied to any other pin	-0.3 to (V_{CC} + 0.3)	V
T_{STG}	Storage temperature range	-65 to +150	°C
T_A	Operating ambient temperature range	-40 to +85	°C

NOTE: Thermal impedance (θ_{JA}) = 117°C/W

DC ELECTRICAL CHARACTERISTICS

V_{CC} = +3V, T_A = 25°C; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
V_{CC}	Power supply voltage range		2.7		5.5	V
I_{CC}	DC current drain	Pin 9 = HIGH or OPEN		3.8	4.5	mA
		V_{CC} = 4.7V		4.4	5.5	mA
	Standby	Pin 9 = LOW		0.11	0.5	mA
	Input current	Pin 9 = LOW	-10		10	µA
		Pin 9 = HIGH	-10		10	
	Input level	Pin 9 = LOW	0		$0.3V_{CC}$	µA
		Pin 9 = HIGH	$0.7V_{CC}$		V_{CC}	
t_{ON}	Power up time	RSSI valid (10% to 90%)		10		µs
t_{OFF}	Power down time	RSSI invalid (90% to 10%)		5		µs

AC ELECTRICAL CHARACTERISTICS

T_A = 25°C; V_{CC} = +3V, unless otherwise stated. RF frequency = 90MHz; RF input step-up = +14.5dBV; IF frequency = 455kHz; RF level = -68dBm. Test circuit Figure 1. The parameters listed below are tested using automatic test equipment to assure consistent electrical characteristics. The limits do not represent the ultimate performance limits of the device. Use of an optimized RF layout will improve many of the listed parameters.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
Mixer/Osc section						
f_{IN}	Input signal frequency			200		MHz
f_{OSC}	Crystal oscillator frequency			200		MHz
NF	Noise figure at 90MHz	Matched input and output		6.2		dB
TOI	Third-order input intercept point	Input matched to 50Ω source		-17		dBm
P1dB	Input 1dB compression point			-27		dBm
	Conversion power gain	Matched 50Ω		7		dB
R_{IN}	Mixer input resistance			2.5		kΩ
C_{IN}	Mixer input capacitance			2.2		pF
R_{OUT}	Mixer output resistance			1.87		kΩ
	Buffered LO output level	LO = 447mV_{P-P}, 1kΩ AC load	100	300	500	mV_{P-P}
IF section						
	IF amp power gain	50Ω source		36		dB
	Limiter power gain	50Ω source		60		dB
IF_{BW}	IF amp bandwidth			2.5		MHz

AC ELECTRICAL CHARACTERISTICS (Continued)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
	RF RSSI output	RF level = -118dBm	.01	0.2	.65	V
		RF level = -68dBm	.4	0.9	1.7	V
		RF level = -28dBm	1.0	1.7	2.3	V
	RSSI range			90		dB
	RSSI accuracy			±1.5		dB
	RSSI ripple			30		mV_{P-P}
	RSSI speed Rise time	No interstage filter		2.5		µs
		With interstage filter		22		µs
	RSSI speed Fall time	No interstage filter		10		µs
		With interstage filter		50		µs
	IF input impedance			1.5		kΩ
	IF output impedance			1.5		kΩ
	Limiter input impedance			1.5		kΩ
	Limiter output impedance	(Pin 10, Pin 11)		200		Ω
	Limiter output signal level	(Pin 10, Pin 11) 1.5kΩ AC load		280		mV_{P-P}
	Limiter output DC level			1.27		V
	Differential output matching			±6		mV
	Differential output offset			±30		mV

CIRCUIT DESCRIPTION

Mixer

The mixer has a balanced input and is capable of being driven single-ended. The input impedance is 2.5kΩ in parallel with a 2.2pF cap at 90MHz RF. The mixer output can drive a 1500Ω ceramic filter at 455kHz or 600kHz directly without any matching required. The mixer conversion power gain is 7dB when both input and output are matched and optimum LO level is used to drive the internal mixer core.

Oscillator and Buffer

The on-board oscillator supplies the signal for the mixer down-conversion. The internally biased transistor can be configured as a Colpitts or Butler overtone crystal oscillator. The transistor's bias current can be increased if desired by adding a shunt resistor from Pin 3 to ground. The oscillator's buffered output (Pin 5) can be used as a feedback signal to lock the oscillator to an appropriate reference.

IF Amplifier and IF Limiter

The IF strip provides more than 95dB of power gain for the down converted signal. Its overall bandwidth is limited to 2MHz. The input and output impedance of the IF amplifier and the input impedance of the IF limiter are set to 1500Ω (match to 455kHz filter). A second filter is connected between the IF amplifier and the limiter for improved channel selectivity and reduced instability. This ceramic filter provides 3dB interstage insertion loss which results in optimal RSSI linearity. The overall gain can be reduced if desired by adding an external attenuator after the IF amplifier. The differential limiter outputs (Pins 10 and 11) are available for demodulator circuits.

RSSI

The received signal strength indicator provides a linear voltage indication of the received signal strength in dB for a range in excess of 90dB. The response time to a change in input signal is less than a few microseconds and the delay is kept to a minimum because of the use of a minimum phase shift circuit. Because of the speed of the RSSI circuit, the RSSI rise and fall time may, in practice, be dominated by the bandwidth of the external bandpass filter that is placed between the mixer and the IF, and the external filter placed between the IF amplifier and limiter. Since the RSSI function requires the signal to propagate through the whole IF strip, and the rise and fall time of the filters are inversely proportional to their bandwidth, there is a trade-off between channel selectivity and RSSI response. A possible solution is to use a second SA637 with wider band external filters for faster RSSI response.

The RSSI curve is temperature compensated and in addition is designed for improved consistency from unit to unit.

The RSSI circuit drives an on-chip low power op amp with rail-to-rail output which can be connected as a unity gain RSSI buffer or a gain stage or even a comparator.

DC Power Supply

The IC is designed for operation between 2.7 and 5.5V. A power supply dependent biasing scheme is used in the mixers to benefit from the large headroom available at higher V_{CC}s.

PERFORMANCE CHARACTERISTICS

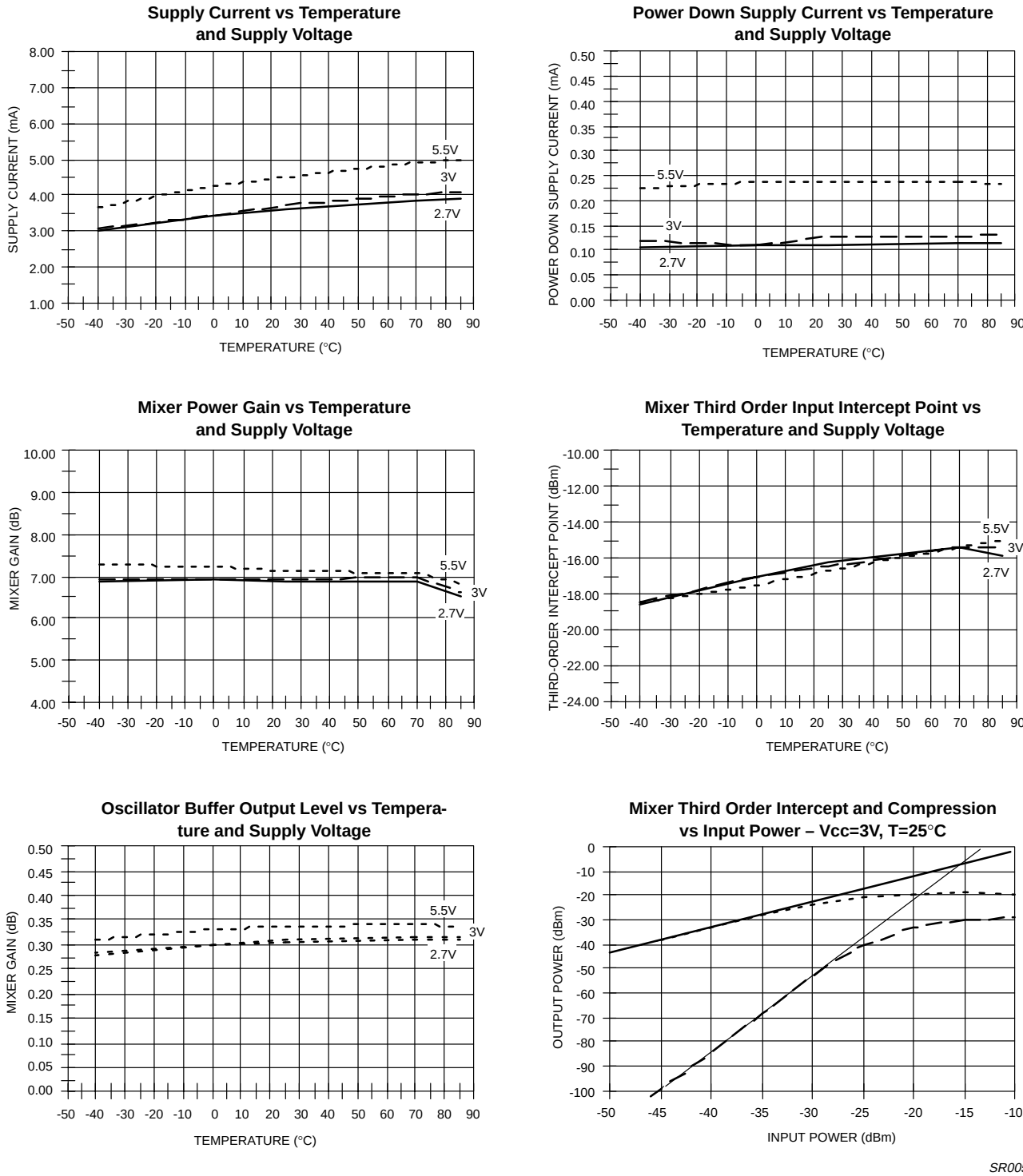
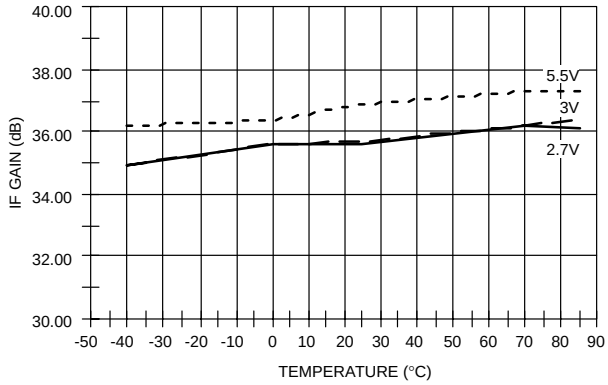


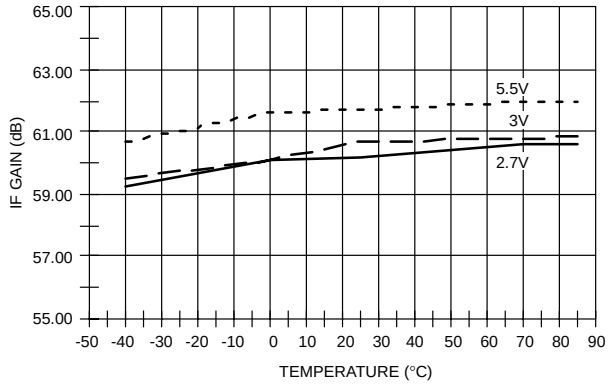
Figure 3. Performance Characteristics

PERFORMANCE CHARACTERISTICS (cont.)

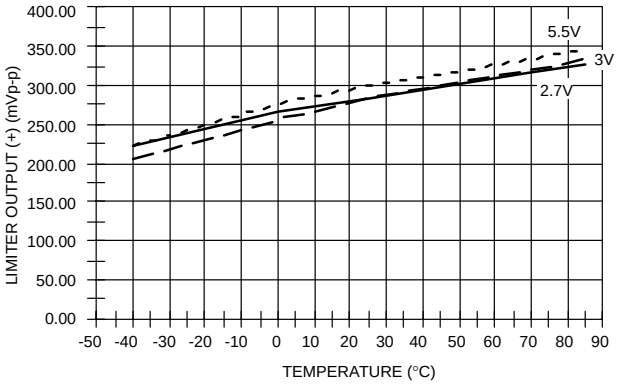
IF Power Gain vs Temperature and Supply Voltage



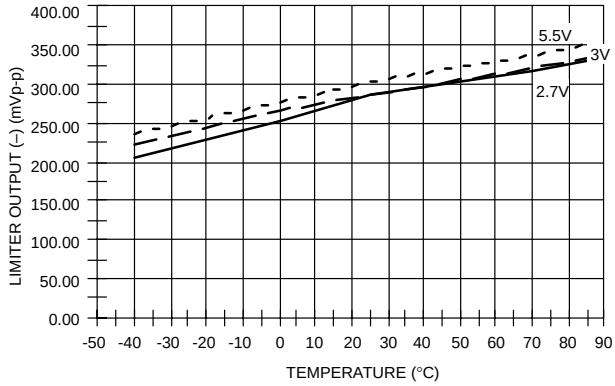
Limiter Power Gain vs Temperature and Supply Voltage



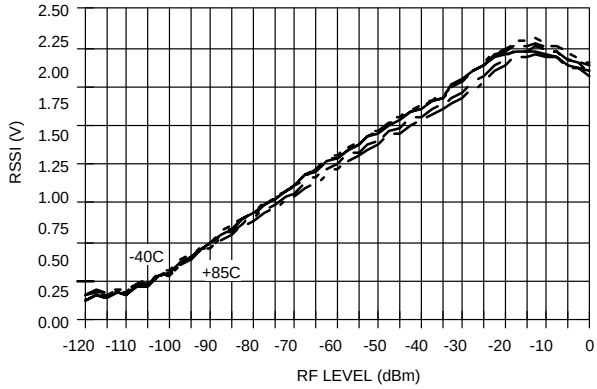
Limiter Output (+) Level vs Temperature and Supply Voltage



Limiter Output (–) Level vs Temperature and Supply Voltage



RSSI vs RF Level and Temperature – V_{CC} = 3V



RSSI vs RF Level and Supply Voltage – Temperature = 25°C

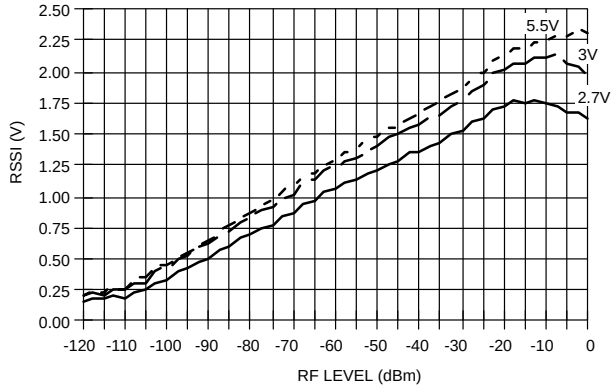


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Figure 4. Performance Characteristics

PIN FUNCTIONS

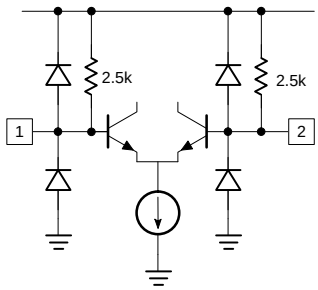
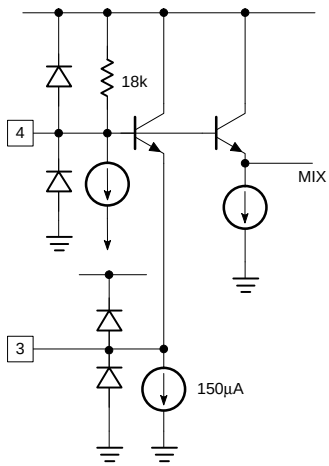
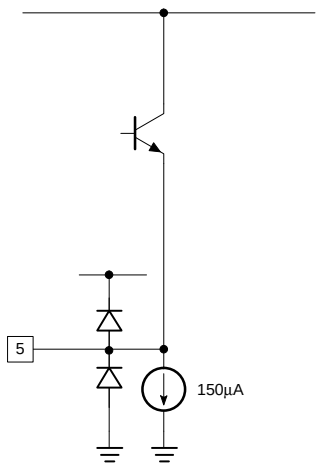
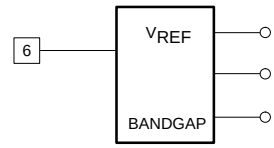
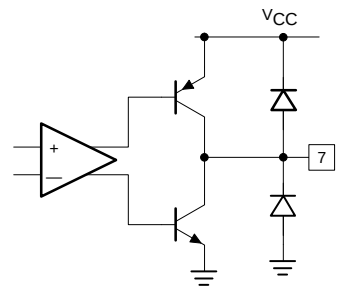
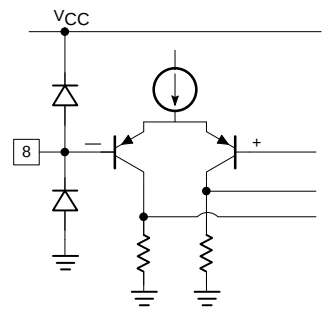
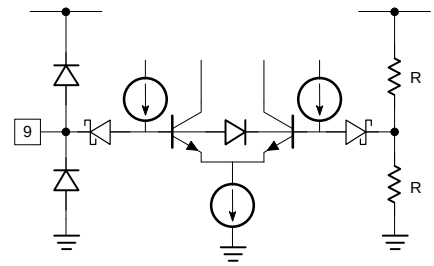
PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT
1	RF IN	+1.40	
2	RF BYPASS	+1.40	
3	OSC E	+1.79	
4	OSC B	+2.56	
5	OSC BUFFER	+1.79	
6	V_{CC}	+3.00	
7	RSSI OUT	+0.20	
8	RSSI FEEDBACK	+0.20	
9	POWER DOWN	+2.00	

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Figure 5. Pin Functions

PIN FUNCTIONS (continued)

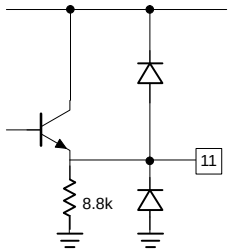
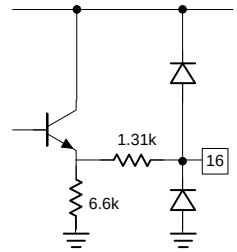
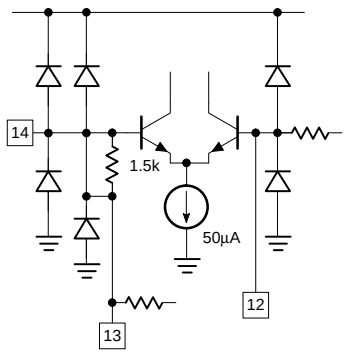
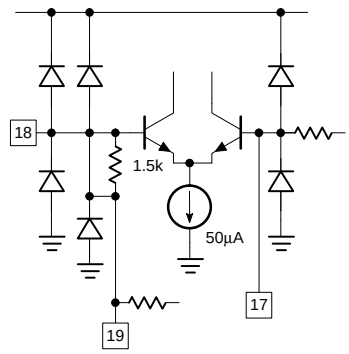
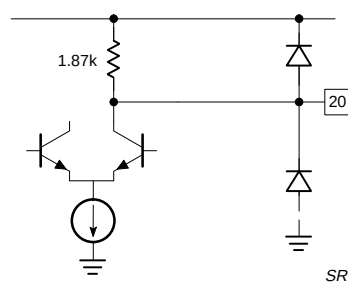
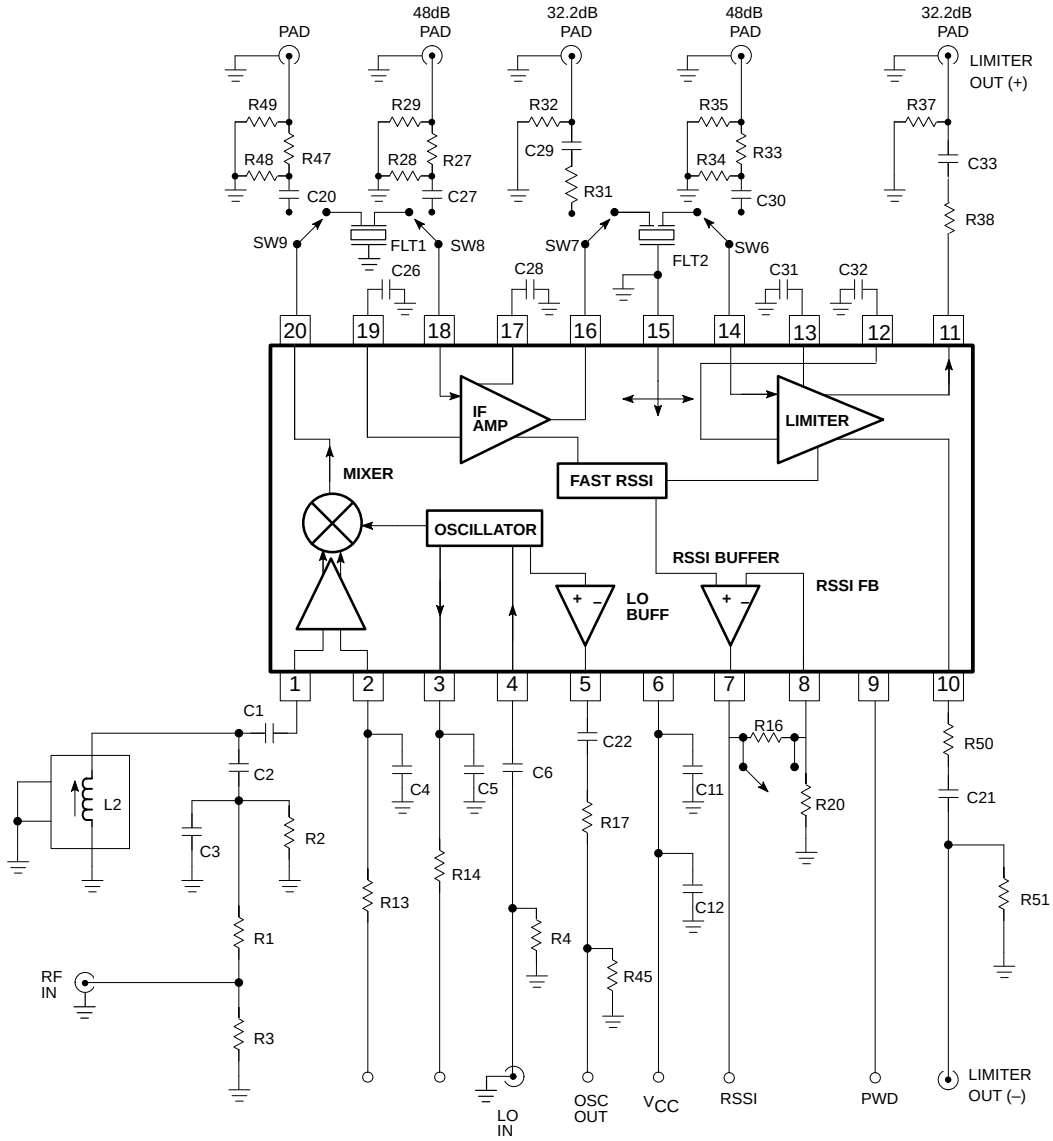
PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT	PIN No.	PIN MNEMONIC	DC V	EQUIVALENT CIRCUIT
10 11	LIMITER OUT	+1.25		16	IF AMP OUT	+1.28	
12	LIMITER DECOUP	+1.28		17	IF AMP DECOUP	+1.28	
13	LIMITER COUPLING	+1.28		18	IF AMP IN	+1.28	
14	LIMITER IN	+1.28		19	IF AMP DECOUP	+1.28	
15	GND	0		20	MIXER OUT	+2.03	

Figure 6. Pin Functions (cont.)

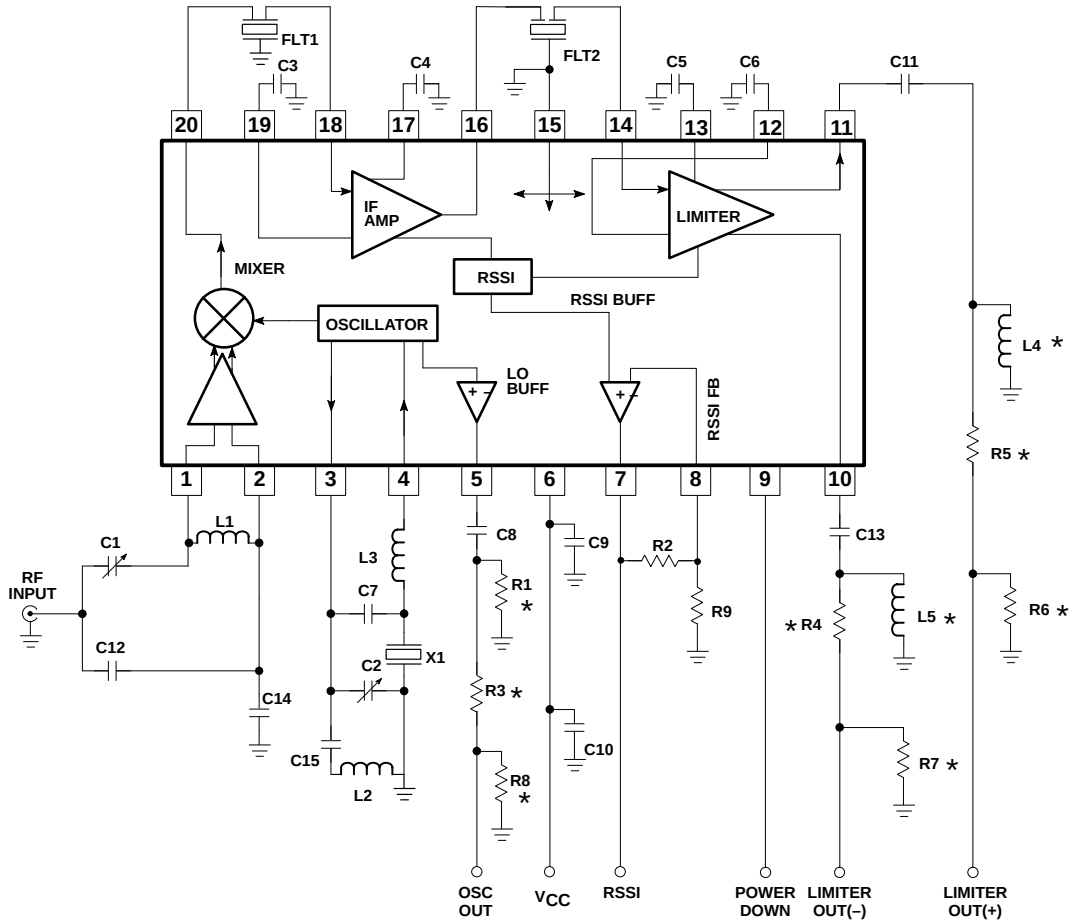


Automatic Test Circuit Component List

C1	**10nF**	**C27**	**100nF**	**R4**	**49.9Ω**	**R32**	**49.9Ω**	**R32**	**49.9Ω**
C2	**91pF**	**C28**	**100nF**	**R13**	**10kΩ**	**R33**	**13.7kΩ**	**R50**	**1kΩ**
C3	**620pF**	**C29**	**100nF**	**R14**	**10kΩ**	**R34**	**1.68kΩ**	**R51**	**49.9Ω**
C4	**100nF**	**C30**	**100nF**	**R16**	**10kΩ**	**R35**	**49.9Ω**	**L2**	**62nH**
C5	**100nF**	**C31**	**100nF**	**R17**	**1kΩ**	**R38**	**1kΩ**		
C6	**10nF**	**C32**	**100nF**	**R20**	**10kΩ**	**R39**	**49.9Ω**		
C11	**100nF**	**C33**	**100nF**	**R27**	**13.7kΩ**	**R45**	**49.9Ω**		
C20	**100nF**	**R1**	**249Ω**	**R28**	**1.68kΩ**	**R47**	**2.43kΩ**		
C21	**100nF**	**R2**	**60.4Ω**	**R29**	**49.9Ω**	**R48**	**39.2kΩ**		
C26	**100nF**	**R3**	**60.4Ω**	**R31**	**1kΩ**	**R49**	**49.9Ω**		

SR00510

Figure 7. SA637 Automatic Test Circuit



Component List

C1	5-30pF	C9	0.1µF	R1	OPEN	L1	0.15µH PM20-R15M
C2	5-30pF	C10	1.0µF	R2	0Ω (short)	L2	0.15µH PM20-R15M
C3	0.1µF	C11	0.1µF	R3	1kΩ	L3	0.47µH PM20-R47M
C4	0.1µF	C12	68pF	R4	1.0kΩ	L4	OPEN
C5	0.1µF	C13	0.1µF	R5	2.0kΩ	L5	OPEN
C6	0.1µF	C14	0.1µF	R6	51Ω	FLT1	455kHz SFGCC 455BX-TC
C7	10pF	C15	1000pF	R7	100Ω	FLT2	455kHz SFGCC 455BX-TC
C8	0.1µF			R8	100Ω	X1	82.705MHz CTS XTAL 020-3249-042
				R9	OPEN		

* NOTE: These components are optional and depend on user matching requirements.
Pads are provided on the demo board.
R2 and R9 set the RSSI buffer gain. For unity gain short R2 (Pin 7 to Pin 8) and leave R9 open.

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Figure 8. SA637 Application Circuit

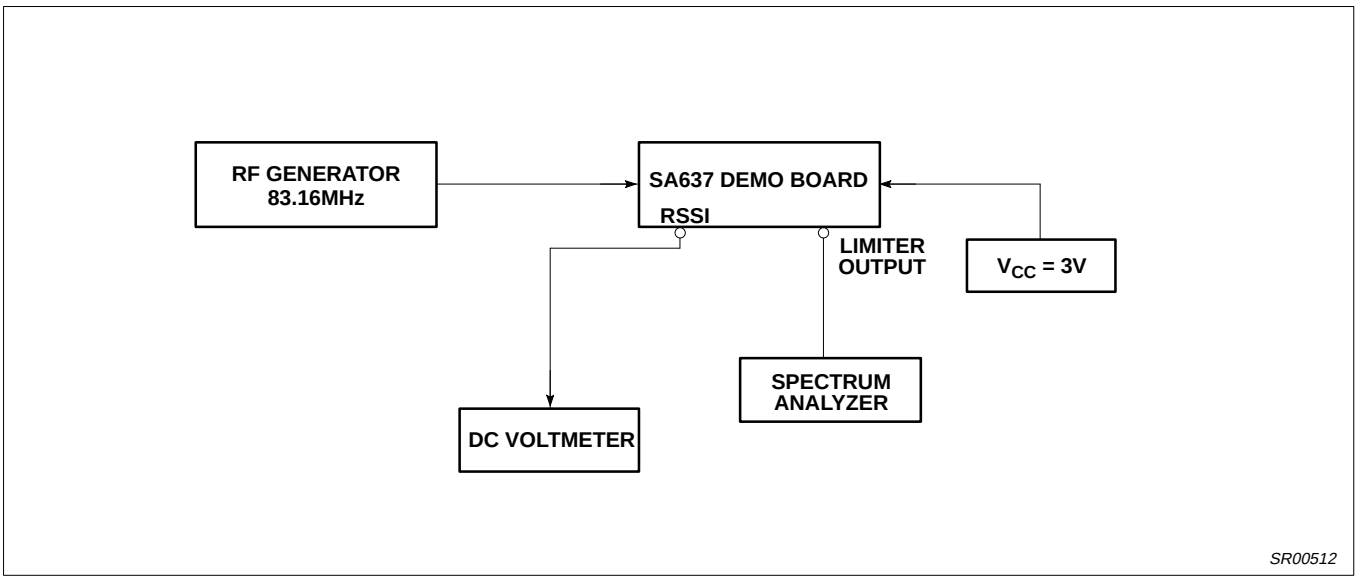

Figure 9. SA637 Application Circuit Test Set Up

NOTES:

1. Carrier-to-Noise (C/N): Connect a spectrum analyzer to Pin 10 or 11; set your RF generator to 83.16MHz or 455kHz above your LO frequency, modulation off; set the spectrum analyzer resolution bandwidth to 300Hz; and adjust your RF input level until the C/N = 26dB. Use video averaging. Assure that LIMOUT(+) and LIMOUT(–) are matched symetrically.
2. Ceramic filters: The ceramic filter can be SFGCC455BX-TC made by Murata which has 30kHz IF bandwidth.
3. Sensitivity: The measured typical sensitivity for 12dB SINAD should be 0.45μV or -114dBm at the RF input.
4. Layout: The layout is very critical in the performance of the receiver. We highly recommend our demo board layout.
5. RSSI: The smallest RSSI voltage (i.e., when no RF input is present and the input is terminated) is a measure of the quality of the layout and design. If the lowest RSSI voltage is 500mV or higher, it means the receiver is in regenerative mode. In that case, the receiver sensitivity will be worse than expected.
6. Supply bypass and shielding: All of the inductors, the quad tank, and their shield must be grounded. A 0.1μF bypass capacitor on the supply pin improves sensitivity.

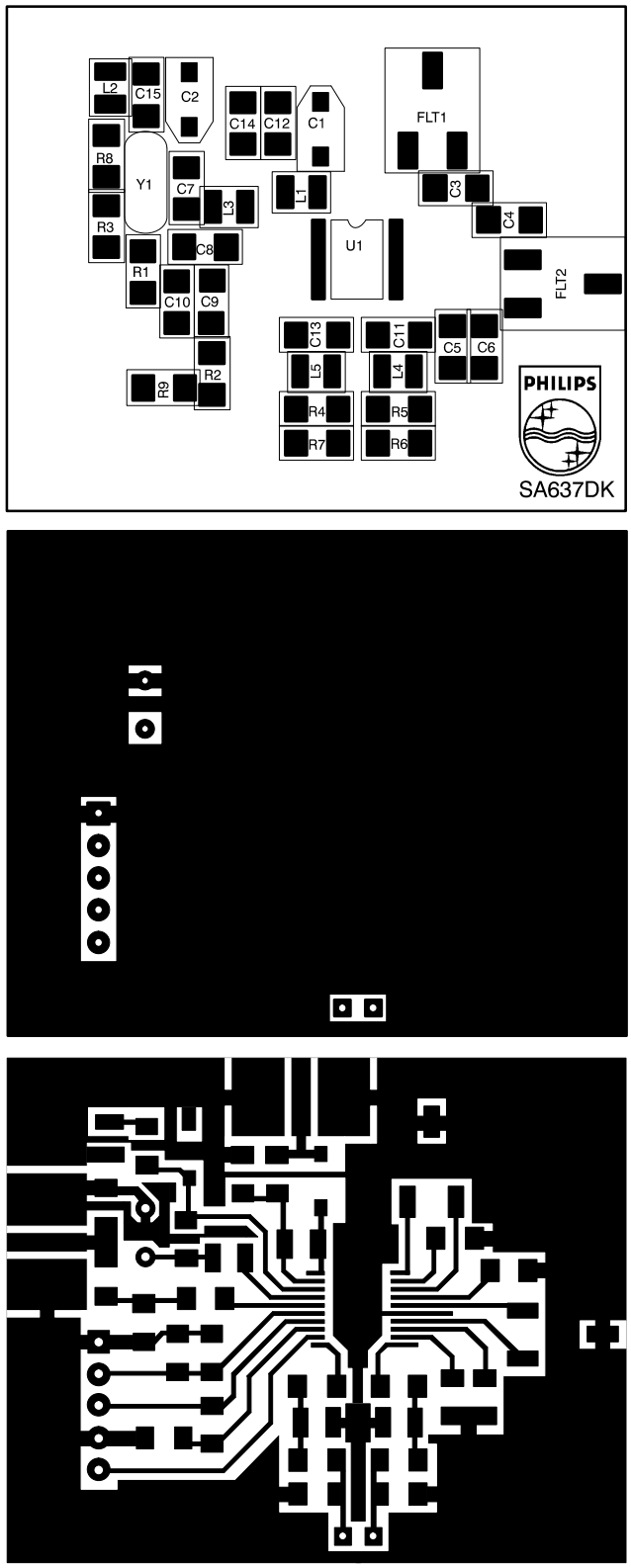

Figure 10. SA637 Board Layout (NOT ACTUAL SIZE)